

74HC112; 74HCT112

Dual JK flip-flop with set and reset; negative-edge trigger

Rev. 3 — 9 August 2016

Product data sheet

1. General description

The 74HC112; 74HCT112 is a dual negative-edge triggered JK flip-flop. It features individual J and K inputs, clock ($\overline{nCP}$) set ($\overline{nSD}$) and reset ($\overline{nRD}$) inputs. It also has complementary $\overline{nQ}$ and $\overline{n\overline{Q}}$ outputs. The set and reset are asynchronous active LOW inputs and operate independently of the clock input. The J and K inputs control the state changes of the flip-flops as described in the mode select function table. The J and K inputs must be stable one set-up time prior to the HIGH-to-LOW clock transition for predictable operation. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

2. Features and benefits

- Input levels:
 - ◆ For 74HC112: CMOS level
 - ◆ For 74HCT112: TTL level
- Asynchronous set and reset
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

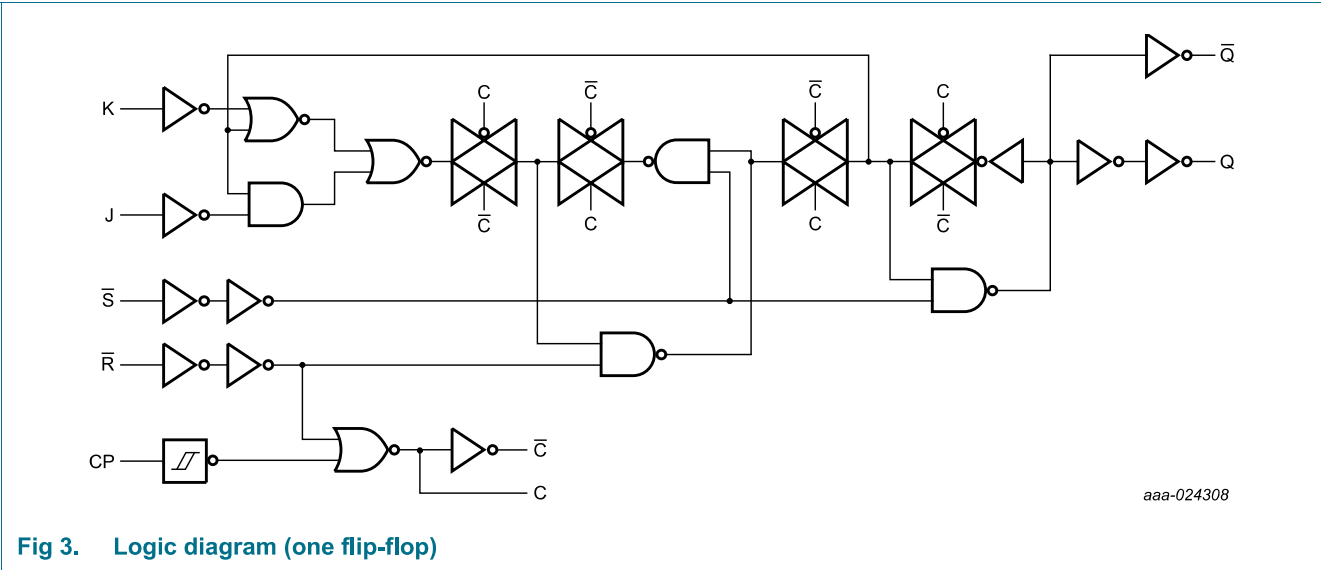
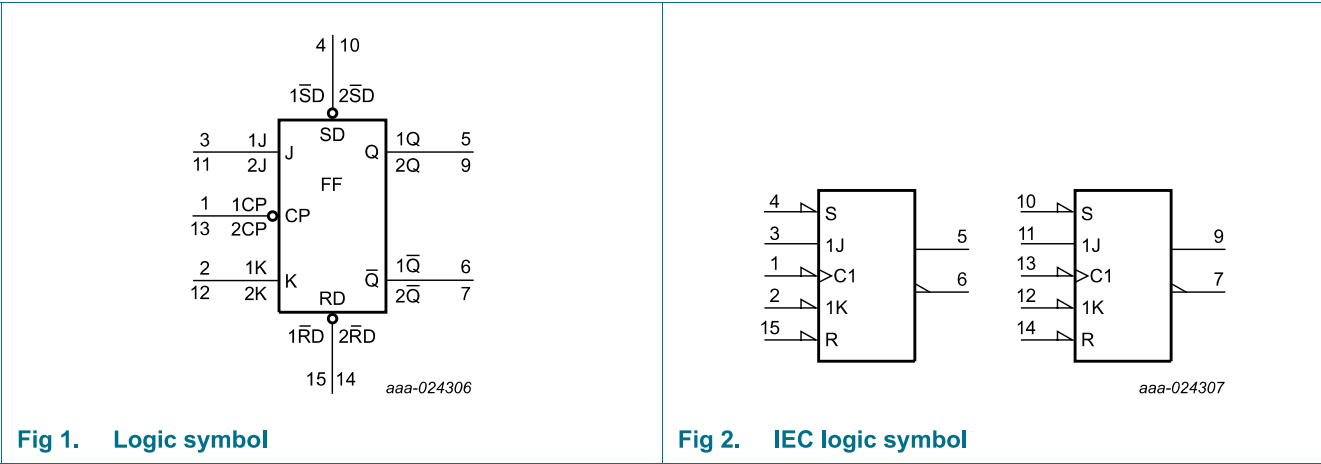
3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC112D	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT112D				
74HC112DB	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HCT112DB				
74HC112PW	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HCT112PW				

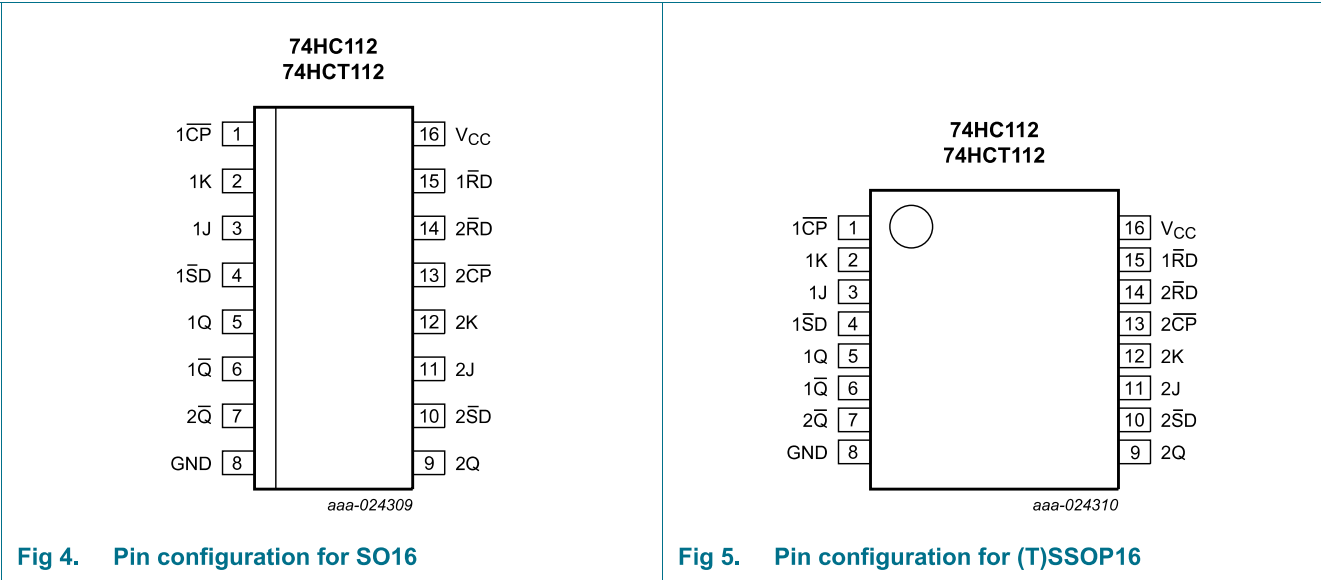


4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1CP, 2CP	1, 13	clock input (HIGH-to-LOW; edge-triggered)
1K, 2K	2, 12	data input
1J, 2J	3, 11	data input
1SD, 2SD	4, 10	set input (active LOW)
1Q, 2Q	5, 9	true flip-flop output
1Q, 2Q	6, 7	complement flip-flop output
GND	8	ground (0 V)
1RD, 2RD	15, 14	reset input (active LOW)
VCC	16	supply voltage

6. Functional description

Table 3. Function selection^[1]

Operating modes	Input					Output	
	nSD	nRD	nCP	nJ	nK	nQ	nQ
Asynchronous set	L	H	X	X	X	H	L
Asynchronous reset	H	L	X	X	X	L	H
Undetermined	L	L	X	X	X	H	L
Toggle	H	H	↓	h	h	$\bar{q}$	q
Load 0 (reset)	H	H	↓	l	h	L	H
Load 1 (set)	H	H	↓	h	l	H	L
Hold no change	H	H	↓	l	l	q	$\bar{q}$

[1] If nSD and nRD simultaneously go from LOW-to-HIGH, the output states are unpredictable.

H = HIGH voltage level

h = HIGH voltage level one set-up time before the HIGH-to-LOW clock transition

L = LOW voltage level

l = LOW voltage level one set-up time before the HIGH-to-LOW clock transition

q = lowercase letters indicate the state of the referenced output one set-up time before the HIGH-to-LOW clock transition

X = don't care

↓ = HIGH-to-LOW clock transition

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		−0.5	+7	V
I _{IK}	input clamping current	V _I < −0.5 V or V _I > V _{CC} + 0.5 V	-	±20	mA
I _{OK}	output clamping current	V _O < −0.5 V or V _O > V _{CC} + 0.5 V	-	±20	mA
I _O	output current	−0.5 V < V _O < V _{CC} + 0.5 V	-	±25	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		−50	-	mA
T _{stg}	storage temperature		−65	+150	°C
P _{tot}	total power dissipation	SO16 and (T)SSOP16 packages ^[1]	-	500	mW

[1] For SO16 packages: above 70 °C, the value of P_{tot} derates linearly with 8 mW/K.

For (T)SSOP16 packages: above 60 °C, the value of P_{tot} derates linearly with 5.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC112			74HCT112			Unit
			Min	Typ	Max	Min	Typ	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V _I	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
V _O	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			−40 °C to +85 °C		−40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
74HC112										
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}								
		I _O = −20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = −20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = −20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = −4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level output voltage	I _O = −5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
		V _I = V _{IH} or V _{IL}								
		I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
		V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	4.0	-	40	-	80	μA

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
C _I	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT112										
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V								
		I _O = –20 µA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = –4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V								
		I _O = 20 µA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 5.5 V	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±0.1	-	±1	-	±1	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	4.0	-	40	-	80	µA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} – 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V								
		nSD inputs	-	50	180	-	225	-	245	µA
		nK inputs	-	60	216	-	270	-	294	µA
		nRD inputs	-	65	236	-	293	-	319	µA
		nJ, and nCP inputs	-	100	360	-	450	-	490	µA
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +85 °C		−40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	Min	Max	
74HC112										
t _{pd}	propagation delay	nCP to nQ; see Figure 6 ^[2]								
		V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
		nCP to nQ; see Figure 6								
		V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
		nRD to nQ, nQ; see Figure 7								
		V _{CC} = 2.0 V	-	58	180	-	225	-	270	ns
		V _{CC} = 4.5 V	-	21	36	-	45	-	54	ns
		V _{CC} = 5 V; C _L = 15 pF	-	18	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	17	31	-	38	-	46	ns
		nSD to nQ, nQ; see Figure 7								
		V _{CC} = 2.0 V	-	50	155	-	295	-	235	ns
		V _{CC} = 4.5 V	-	18	31	-	39	-	47	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	40	ns
t _t	transition time	nQ, nQ; see Figure 6 ^[3]								
		V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t _w	pulse width	nCP HIGH or LOW; see Figure 6								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		nSD, nRD LOW; see Figure 7								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns		

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	Min	Max	
t_{rec}	recovery time	$\overline{nRD}$ to $\overline{nCP}$; see Figure 7								
		$V_{CC} = 2.0$ V	80	22	-	125	-	150	-	ns
		$V_{CC} = 4.5$ V	16	8	-	25	-	30	-	ns
		$V_{CC} = 6.0$ V	14	6	-	21	-	26	-	ns
		$\overline{nSD}$ to $\overline{nCP}$; see Figure 7								
		$V_{CC} = 2.0$ V	80	–19	-	100	-	120	-	ns
		$V_{CC} = 4.5$ V	16	–7	-	20	-	24	-	ns
		$V_{CC} = 6.0$ V	14	–6	-	17	-	20	-	ns
t_{su}	set-up time	nJ and nK to $\overline{nCP}$; see Figure 6								
		$V_{CC} = 2.0$ V	80	19	-	100	-	120	-	ns
		$V_{CC} = 4.5$ V	16	7	-	20	-	24	-	ns
		$V_{CC} = 6.0$ V	14	6	-	17	-	20	-	ns
t_h	hold time	nJ and nK to $\overline{nCP}$; see Figure 6								
		$V_{CC} = 2.0$ V	0	–11	-	0	-	0	-	ns
		$V_{CC} = 4.5$ V	0	–4	-	0	-	0	-	ns
		$V_{CC} = 6.0$ V	0	–3	-	0	-	0	-	ns
f_{max}	maximum frequency	$\overline{nCP}$; see Figure 6								
		$V_{CC} = 2.0$ V	6	20	-	4.8	-	4.0	-	MHz
		$V_{CC} = 4.5$ V	30	60	-	24	-	20	-	MHz
		$V_{CC} = 5$ V; $C_L = 15$ pF	-	66	-	-	-	-	-	MHz
		$V_{CC} = 6.0$ V	35	71	-	28	-	24	-	MHz
C_{PD}	power dissipation capacitance	$C_L = 50$ pF; $f = 1$ MHz; $V_I = \text{GND to } V_{CC}$ [4]	-	27	-			-	-	pF

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +85 °C		−40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	Min	Max	
74HCT112										
t _{pd}	propagation delay	nCP to nQ; see Figure 6 ^[2]								
		V _{CC} = 4.5 V	-	21	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
		nCP to nQ; see Figure 6 ^[2]								
		V _{CC} = 4.5 V	-	23	40	-	50	-	60	ns
		V _{CC} = 5 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
		nRD to nQ, nQ; see Figure 7								
		V _{CC} = 4.5 V	-	22	37	-	46	-	56	ns
		V _{CC} = 5 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
		nSD to nQ, nQ; see Figure 7								
		V _{CC} = 4.5 V	-	18	32	-	40	-	48	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
t _t	transition time	nQ, nQ; see Figure 6 ^[3]								
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _w	pulse width	nCP HIGH or LOW; see Figure 6								
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		nSD, nRD LOW; see Figure 7								
		V _{CC} = 4.5 V	18	10	-	23	-	27	-	ns
t _{rec}	recovery time	nRD to nCP; see Figure 7								
		V _{CC} = 4.5 V	20	11	-	25	-	30	-	ns
		nSD to nCP; see Figure 7								
		V _{CC} = 4.5 V	20	−8	-	25	-	30	-	ns
t _{su}	set-up time	nJ and nK to nCP; see Figure 6								
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
t _h	hold time	nJ and nK to nCP; see Figure 6								
		V _{CC} = 4.5 V	0	−7	-	0	-	0	-	ns
f _{max}	maximum frequency	nCP; see Figure 6								
		V _{CC} = 4.5 V	30	64	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	70	-	-	-	-	-	MHz

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	Min	Max	
C_{PD}	power dissipation capacitance	$C_L = 50$ pF; $f = 1$ MHz; [4] $V_I = \text{GND to } V_{CC}$	-	30	-	-	-	-	-	pF

[1] All typical values are measured at $T_{amb} = 25$ °C.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] t_t is the same as t_{THL} and t_{TLH} .

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

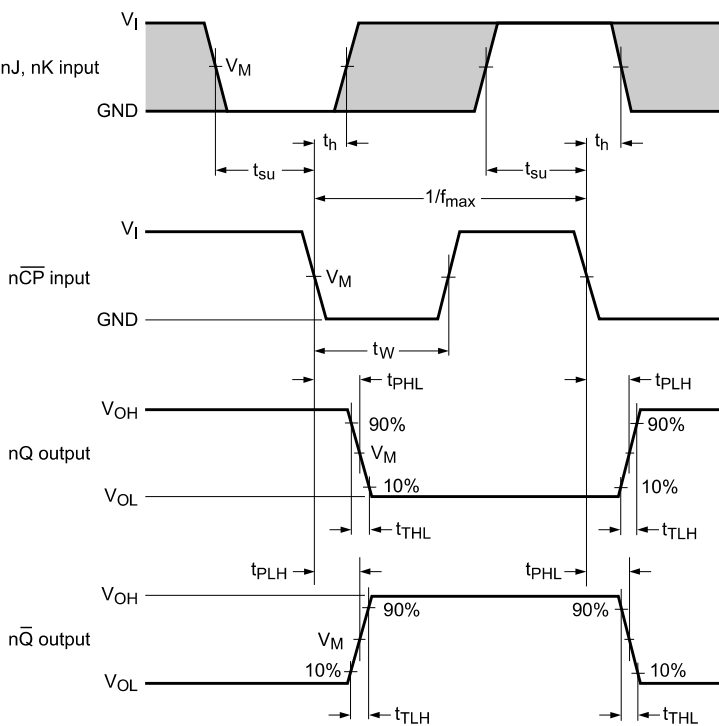
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

11. Waveforms



aaa-024311

Measurement points are given in [Table 8](#).
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 6. Clock propagation delays, output transition time, pulse width, set-up, hold times, and maximum frequency

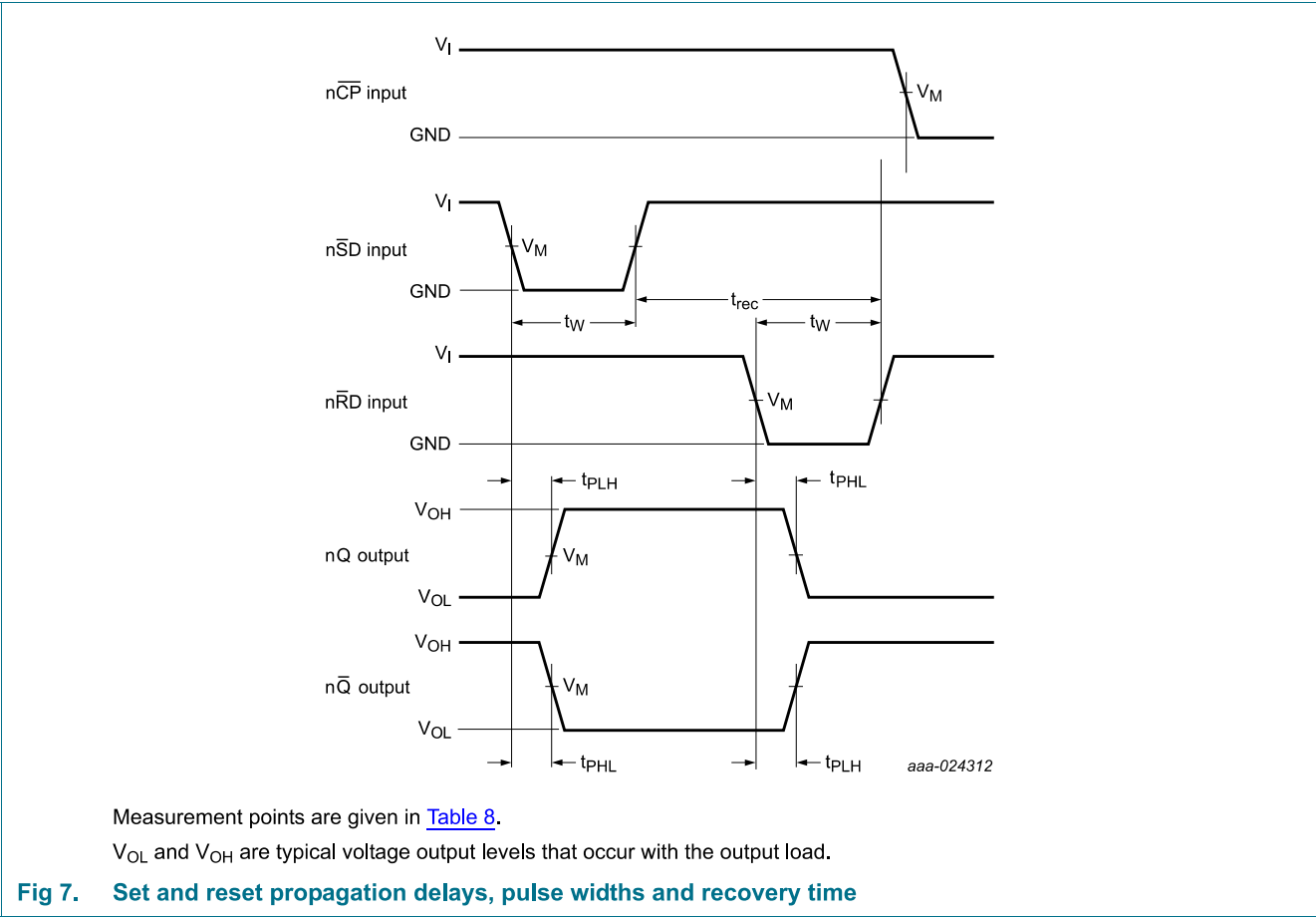
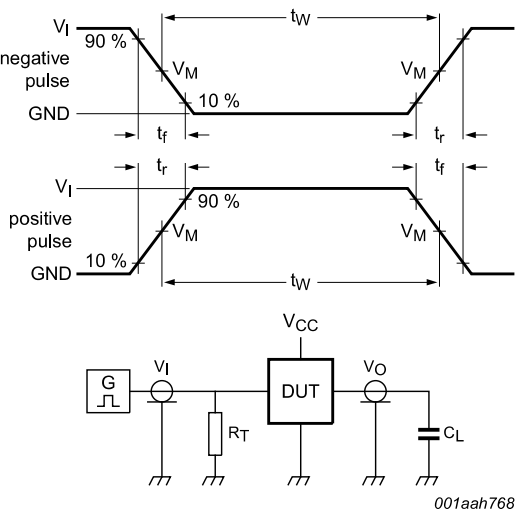


Table 8. Measurement points

Type	Input	Output
	V_M	V_M
74HC112	$0.5V_{CC}$	$0.5V_{CC}$
74HCT112	1.3 V	1.3 V



Test data is given in [Table 9](#).
Definitions test circuit:
 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.
 C_L = Load capacitance including jig and probe capacitance.

Fig 8. Test circuit for measuring switching times

Table 9. Test data

Type	Input		Load	Test
	V_I	t_r, t_f	C_L	
74HC112	V_{CC}	6 ns	15 pF, 50 pF	t_{PLH}, t_{PHL}
74HCT112	3 V	6 ns	15 pF, 50 pF	t_{PLH}, t_{PHL}

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

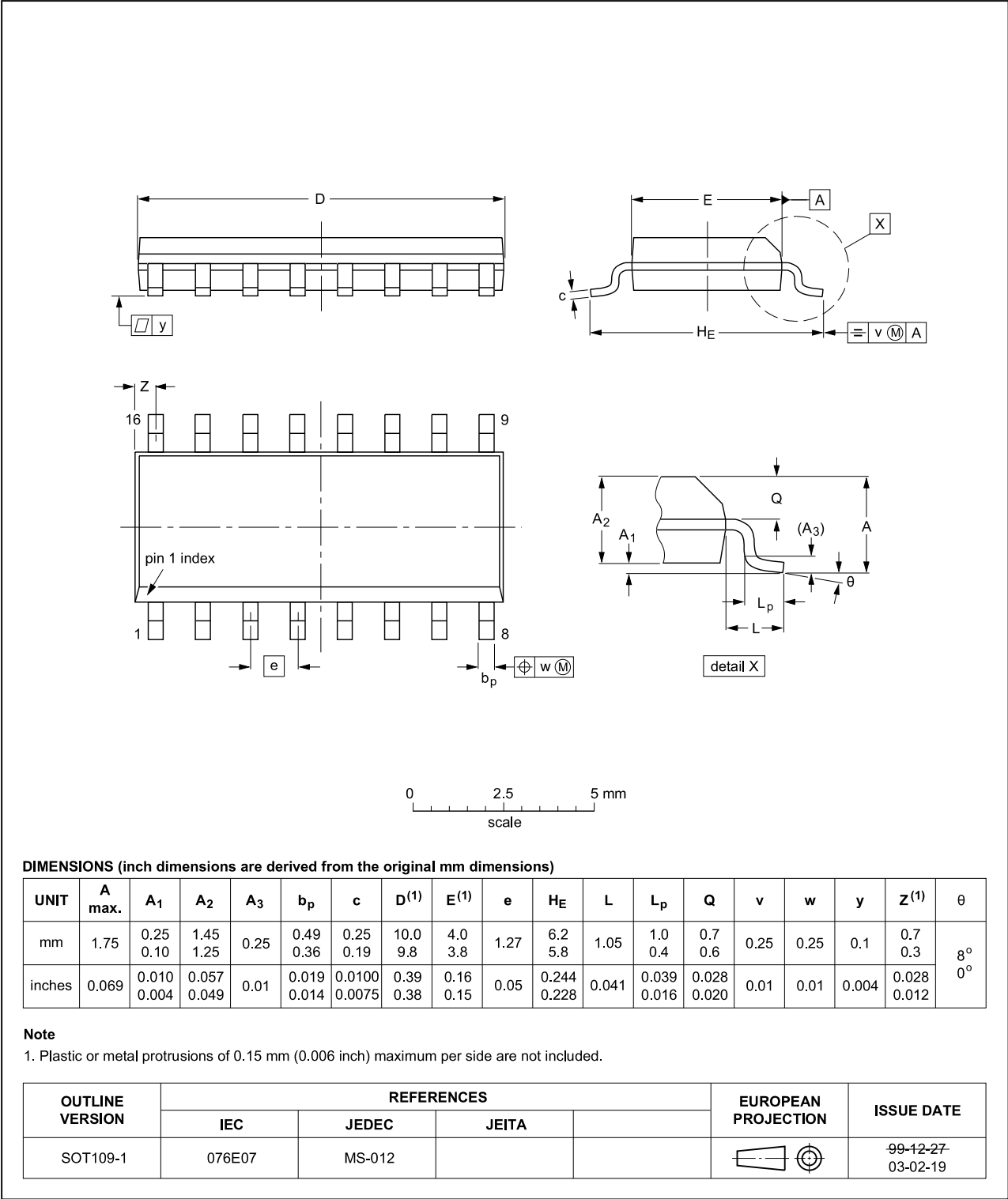


Fig 9. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

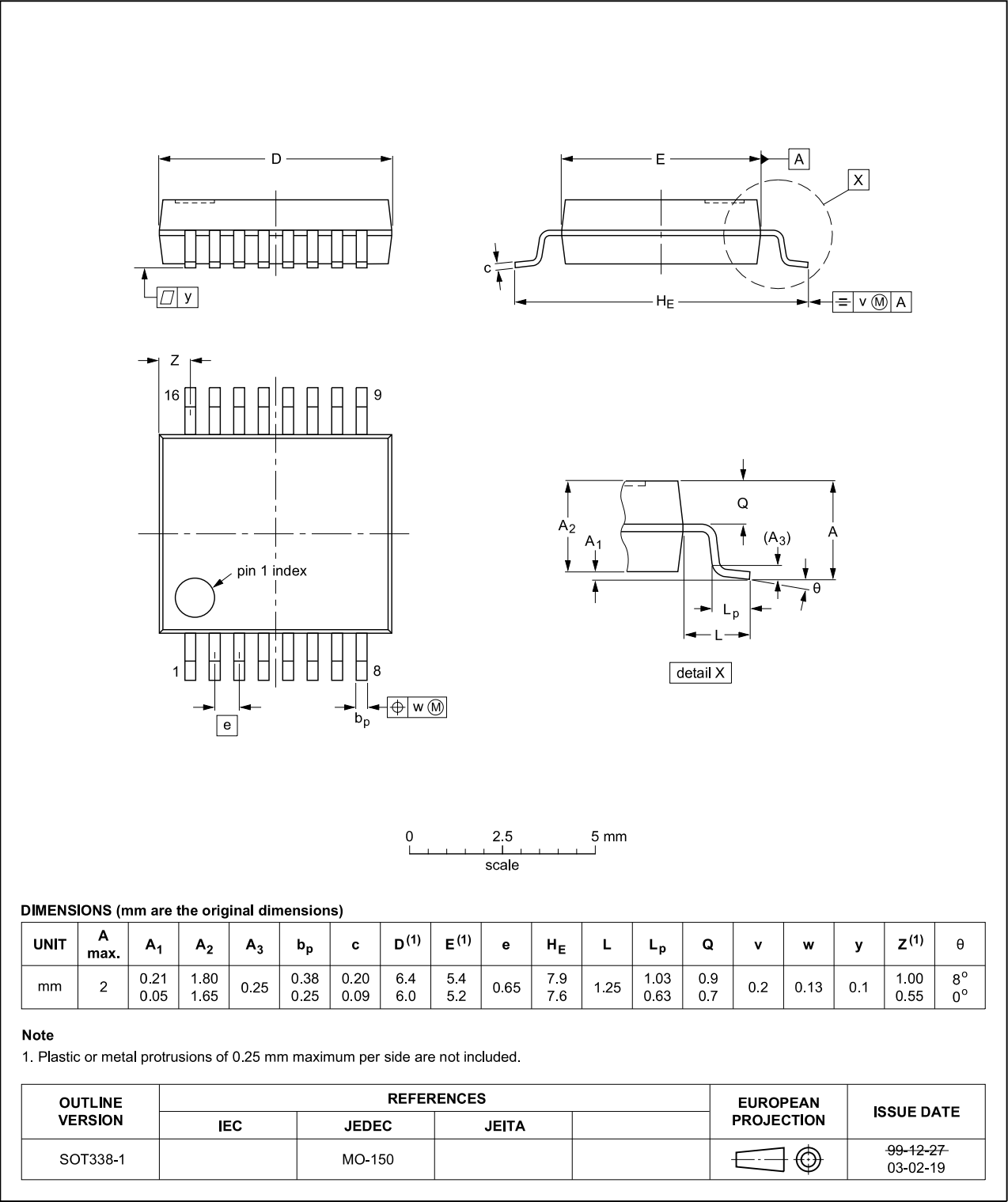


Fig 10. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

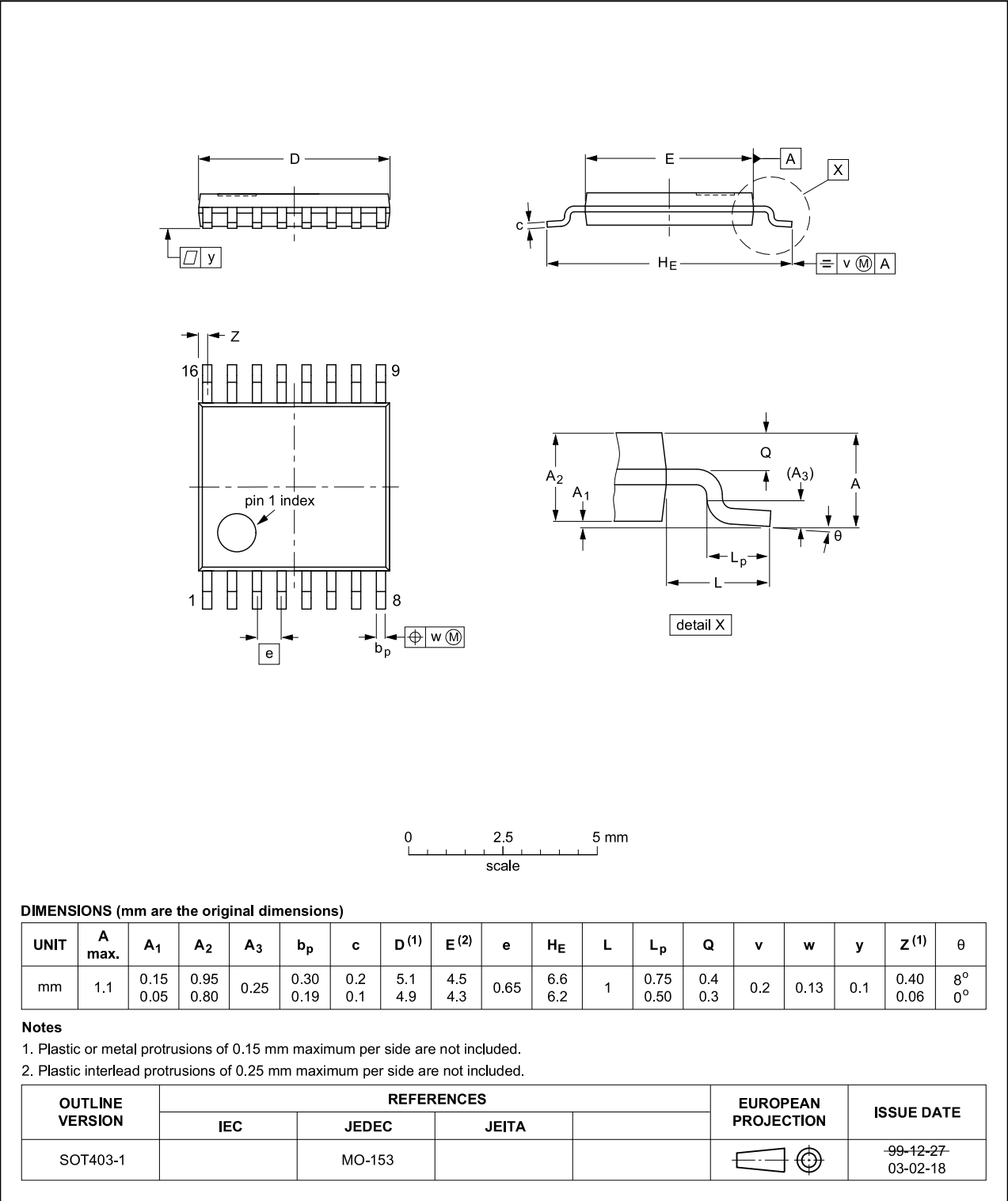


Fig 11. Package outline SOT403-1 (TSSOP16)